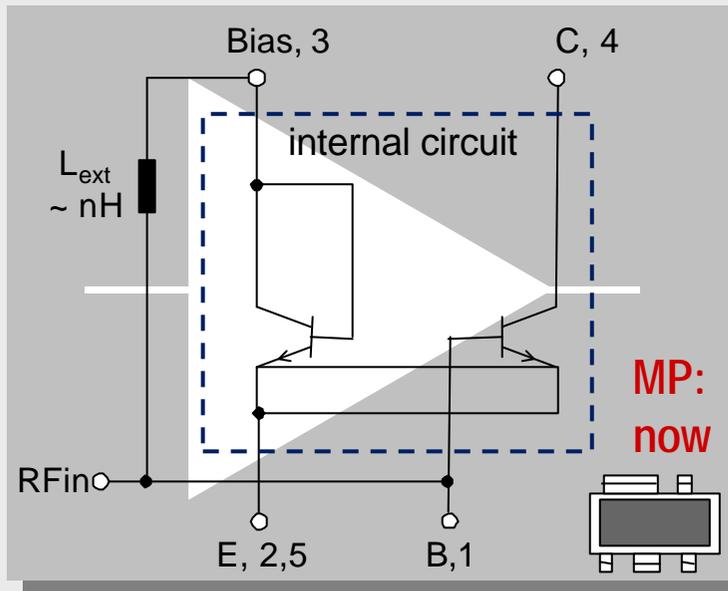
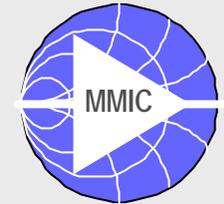


BGB550

Medium power broadband amplifier

NEW



Features and Benefits

- mirror biased RF transistor
- collector current up to **350mA**
- low operation voltage $V_{CC} < 3V$
- high output power & linearity
- input matching improved by L_{ext}
- SCT595 package

$V_d = 2.0V, I_d = 100mA$

Symbol	Parameter	frequency	Unit	Value
IS21I² / (G_{MA})	Power Gain / (max. available)	900 MHz	dB	17 (22)
		1.8 GHz		11 (16)
NF	Noise Figure	900 MHz	dB	1.3
		1.8 GHz		1.5
P-1dB	Output Compression Point	900 MHz	dBm	19
		1.8 GHz		19
OIP3	Output Third Order Intercept Point	900 MHz	dBm	28
		1.8 GHz		28

stop thinking never